

STTH8003CY

HIGH FREQUENCY SECONDARY RECTIFIERS

PRELIMINARY DATASHEET

MAJOR PRODUCTS CHARACTERISTICS

I _{F(AV)}	2x40 A
V _{RRM}	300 V
V _F (max)	1 V
trr (max)	60 ns

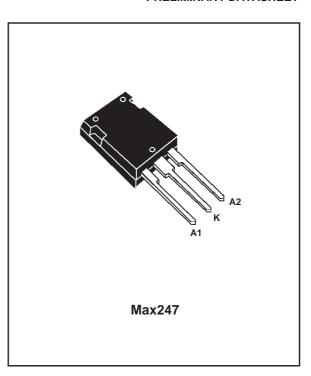
FEATURES AND BENEFITS

- COMBINES HIGHEST RECOVERY AND VOLTAGE PERFORMANCE.
- ULTRA-FAST, SOFT AND NOISE-FREE RECOVERY.
- HIGH OPERATING TEMPERATURE THANKS TO LOW LEAKAGE CURRENT.

DESCRIPTION

Dual rectifiers suited for Switch Mode Power Supply and high frequency DC to DC converters.

Packaged in Max247, this device is intended for use in low voltage, high frequency inverters, free wheeling operation, welding equipment and telecom power supplies.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			300	V
I _{F(RMS)}	RMS forward current			50	А
I _{F(AV)}	Average forward current	$Tc = 105^{\circ}C$ Per diode $\delta = 0.5$ Per device		40 80	А
IFSM	Surge non repetitive forward current tp = 10 ms sinusoidal			400	А
I _{RSM}	Non repetitive avalanche current tp = 100 μs square			4	А
T _{stg}	Storage temperature range			-55 +150	°C
Tj	Maximum operating junction temperature			+ 150	°C

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THERMAL RESISTANCES

Symbol	Parameter Parameter		Value	Unit
R _{th (j-c)}	Junction to case thermal resistance	Per diode Total	0.8 0.5	°C/W
R _{th (c)}		Coupling	0.2	°C/W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests Conditions		Min.	Тур.	Max.	Unit
I _R *	Reverse leakage current	V _R = 300 V	Tj = 25°C			80	μΑ
			Tj = 125°C		80	800	
VF **	Forward voltage drop	I _F = 40 A	Tj = 25°C			1.25	V
			Tj = 125°C		0.85	1	

Pulse test : * tp = 5 ms, δ < 2 % ** tp = 380 μ s, δ < 2%

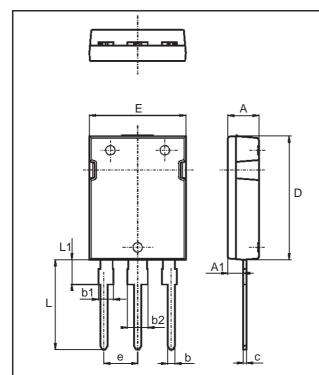
To evaluate the maximum conduction losses use the following equation : P = 0.75 x $I_{F(AV)}$ + 0.0062 $I_{F(RMS)}^{\,\,\,2}$

DYNAMIC ELECTRICAL CHARACTERISTICS

Symbol	Tests Conditions			Тур.	Max.	Unit
trr	$I_F = 0.5 \text{ A}$ $I_{rr} = 0.25 \text{ A}$ $I_R = 1 \text{ A}$			50	ns	
	$I_F = 1 \text{ A}$ $dI_F/dt = -50 \text{ A/}\mu\text{s}$ $V_R = 30 \text{ V}$				60	
I _{RM}	$Vcc = 200 \text{ V}$ $I_F = 40 \text{ A}$ $d_{IF}/dt = -200 \text{ A/}\mu\text{s}$	Tj = 125°C			13	А
Sfactor				0.3		
tfr	$I_F = 40 \text{ A}$ $dI_F/dt = 200 \text{ A}/\mu\text{s}$,	Tj = 25°C			450	ns
V _{FP}	$V_{FR} = 1.1 \times V_F \text{ max}$				5	V

PACKAGE MECHANICAL DATA

Max247



	DIMENSIONS				
REF.	Millin	neters	Inches		
	Min.	Max.	Min.	Max.	
Α	4.70	5.30	0.185	0.209	
A1	2.20	2.60	0.087	0.102	
b	1.00	1.40	0.038	0.055	
b1	2.00	2.40	0.079	0.094	
b2	3.00	3.40	0.118	0.133	
С	0.40	0.80	0.016	0.031	
D	19.70	10.30	0.776	0.799	
е	5.35	5.55	0.211	0.219	
E	15.30	15.90	0.602	0.626	
L	14.20	15.20	0.559	0.598	
L1	3.70	4.30	0.146	0.169	

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH8003CY	STTH8003CY	Max247	4.4 g.	30	Tube

- Cooling method: C
- Epoxy meets UL94,V0

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